



**Product data sheet** 

#### 1. General description

Hyperfast power diode in a SOD59 (2-lead TO-220AC) plastic package.

#### 2. Features and benefits

- · Extremely fast switching
- Low reverse recovery current
- Low thermal resistance
- Reduces switching losses in associated MOSFET

#### 3. Applications

- Continuous Current Mode (CCM) Power
- Half-bridge or full-bridge switched-mode
- Half-bridge lighting ballasts

#### 4. Quick reference data

Table 1. Q	uick reference data						
Symbol	Parameter	Conditions	Values			Unit	
Absolute	maximum rating						
$V_{\text{RRM}}$	repetitive peak reverse voltage			600			V
$I_{\rm F(AV)}$	average forward current	δ = 0.5 ; square-wave pulse; T <sub>mb</sub> ≤ 98 °C; Fig. 1; Fig. 2		15			A
I <sub>FRM</sub>	repetitive peak forward current	δ = 0.5 ; t <sub>p</sub> = 25 μs; T <sub>mb</sub> ≤ 98 °C; square-wave pulse	30		A		
I <sub>FSM</sub>	non-repetitive peak	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	200			А	
	forward current	$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	220		А		
Symbol	Parameter	Conditions	Min Typ Max		Unit		
Static ch	aracteristics						
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 15 A; T <sub>j</sub> = 150 °C; <u>Fig. 3</u>	- 1.4 2		2	V	
Dynamic	characteristics						
t <sub>rr</sub>	reverse recovery time	$I_F = 15 \text{ A}; V_R = 400 \text{ V}; \text{ d}I_F/\text{d}t = 500 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; \text{ Fig. 4}$		-	19	-	ns

## 5. Pinning information

Table 2.	Pinning infor	mation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	mb	
2	A	anode	7 709	К <u></u> А 001ааа020
mb	mb	mounting base; cathode	C	001aaa020

## 6. Ordering information

Table 3. Ordering information						
Type number	Package	je				
	Name	Description	Version			
BYC15-600	TO-220AC	plastic single-ended package; heatsink mounted; 1 mounting hole; 2-lead TO-220AC	SOD59			

## 7. Marking

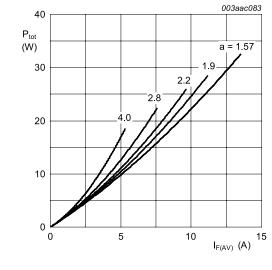
Table 4. Marking codes						
Type number	Marking codes					
BYC15-600	BYC15-600					

### 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V <sub>RRM</sub>	repetitive peak reverse voltage		600	V
V <sub>RWM</sub>	crest working reverse voltage		600	V
V <sub>R</sub>	reverse voltage	T <sub>mb</sub> ≤ 100 °C; DC	500	V
I <sub>F(AV)</sub>	average forward current	δ = 0.5 ; square-wave pulse; T <sub>mb</sub> ≤ 98 °C; Fig. 1; Fig. 2	15	A
I <sub>FRM</sub>	repetitive peak forward current	δ = 0.5 ; t <sub>p</sub> = 25 μs; T <sub>mb</sub> ≤ 98 °C; square-wave pulse	30	A
I <sub>FSM</sub>	non-repetitive peak	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	200	А
	forward current	$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	220	А
T <sub>stg</sub>	storage temperature		-40 to 150	°C
Tj	junction temperature		150	°C



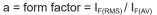


Fig. 1. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

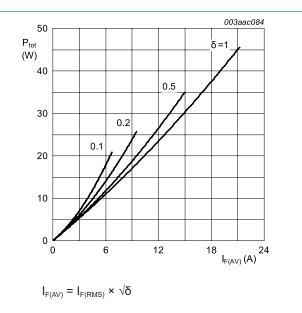


Fig. 2. Forward power dissipation as a function of average forward current; square waveform; maximum values

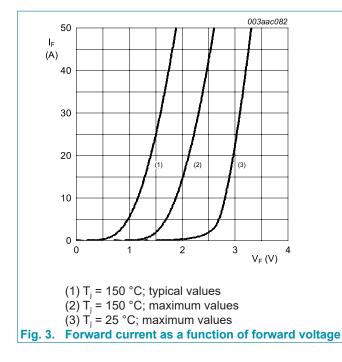
### 9. Thermal characteristics

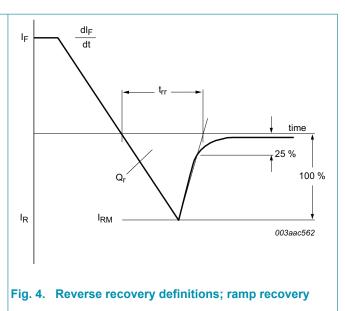
#### Table 6. Thermal characteristics

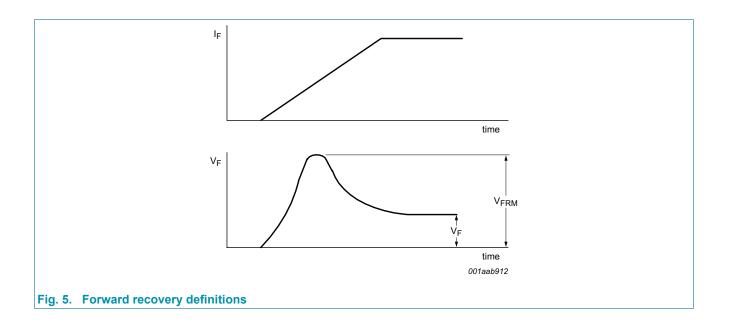
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	with heatsink compound	-	-	1.5	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	-	60	-	K/W

### **10. Characteristics**

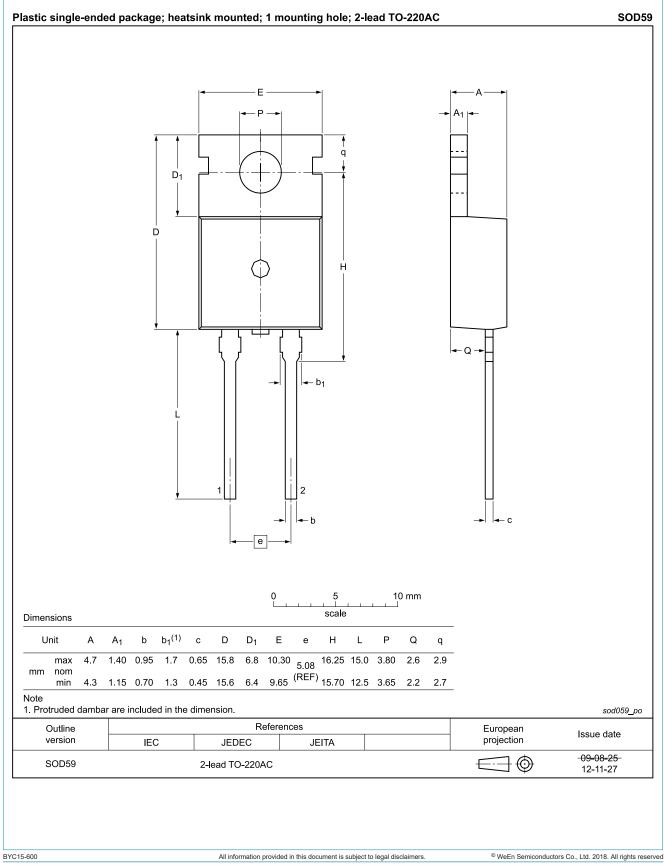
Table 7. Cl	naracteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 30A; T <sub>j</sub> = 150 °C; <u>Fig. 3</u>	-	1.7	2.3	V
		I <sub>F</sub> = 15 A; T <sub>j</sub> = 25 °C; <u>Fig. 3</u>	-	1.9	2.9	V
		I <sub>F</sub> = 15 A; T <sub>j</sub> = 150 °C; <u>Fig. 3</u>	-	1.4	2	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 600 V; T <sub>j</sub> = 25 °C	-	12	200	μA
		V <sub>R</sub> = 500 V; T <sub>j</sub> = 100 °C	-	1.1	3	mA
Dynamic	characteristics	· · · · · ·	· · ·			
t <sub>rr</sub>	reverse recovery time	$I_{F} = 15 \text{ A}; V_{R} = 400 \text{ V}; \text{ d}I_{F}/\text{d}t = 500 \text{ A}/\mu\text{s};$ T_{j} = 100 °C; Fig. 4	-	32	40	ns
		$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 50 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; \text{ Fig. 4}$	-	35	55	ns
		$I_F = 15 \text{ A}; V_R = 400 \text{ V}; \text{ d}I_F/\text{d}t = 500 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; \text{ Fig. 4}$	-	19	-	ns
I <sub>RM</sub>	peak reverse recovery current	$I_F = 15 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A}/\mu\text{s};$ $T_j = 125 \text{ °C}; Fig. 4$	-	9.5	12	A
		$I_F = 15 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 50 \text{ A}/\mu\text{s};$ $T_j = 125 \text{ °C}; Fig. 4$	-	3	7.5	A
$V_{FR}$	forward recovery voltage	I <sub>F</sub> = 15 A; dI <sub>F</sub> /dt = 100 A/μs; T <sub>j</sub> = 25 °C; <u>Fig. 5</u>	-	8	11	V







### **11. Package outline**



## **12. Revision history**

#### Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes				
BYC15-600 v.3	20180224	Product data sheet	-	BYC15-600 v.2				
Modifications:	Change from NXP version to WeEn version							
BYC15-600 v.2	20100729	Product data sheet	-	BYC15-600 v.1				
Modifications:	Various changes to content.							
BYC15-600 v.1	20071129	Product data sheet	-	-				

## BYC15-600

#### Hyperfast power diode

### 13. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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